SBES023A - SEPTEMBER 2011 - REVISED OCTOBER 2011





# Low-Power, High-Speed Buffer for CCD Sensor

Check for Samples: VSP1000

### **FEATURES**

- **High Speed:** 
  - 210 MHz, 3-dB Bandwidth
- **Fast Settling Time**
- **Adjustable Active Load Current**
- **Adjustable Drive Strength**
- Low Power: 20 mW
- **Ultra-Small Package:** 
  - 1-mm × 1-mm Ultra-Thin 0.35-mm QFN

## **DESCRIPTION**

The VSP1000 is a high-speed, low-noise, low-power, fast-settling, unity-gain buffer. It is specially designed for use between charge-coupled device (CCD) sensors and analog front-ends (AFEs). The device has an adjustable active load current that can load the CCD sensor output appropriately. The VSP1000 also features an adjustable output drive strength that can be set in accordance with the bandwidth requirements. At a 2-mA drive current, the device provides a bandwidth of 210 MHz, which allows for very low power operation with good performance. An ultra-small package of 1 mm × 1 mm and 0.35-mm height helps in saving printed circuit board (PCB) space and achieving a very low profile.

The VSP1000 is ideal for driving Texas Instruments AFEs for CCD sensors and, in general, any analog-to-digital converter (ADC) inputs. adjustable load current allows for easy interfacing with a variety of CCD sensors from various manufacturers.

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

# PACKAGE/ORDERING INFORMATION(1)

PRODUCT	PACKAGE- LEAD	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
VSP1000	OEN 6	Dec	000 +- 10500	VCD4000DCE	VSP1000DSFT	Tape and Reel, 250
VSP1000	QFN-6	DSF	0°C to +85°C	VSP1000DSF	VSP1000DSFR	Tape and Reel, 5000

<sup>(1)</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or visit the device product folder at www.ti.com.

# ABSOLUTE MAXIMUM RATINGS(1)

Over free-air temperature range, unless otherwise noted.

		VSP1000	UNIT
Supply voltage	VCC	20.0	V
Input voltage		-0.3 to VCC + 0.3	V
Input current	Any pin except supplies	±10	mA
Ambient temperature under	bias	-25 to +85	°C
Storage temperature		−55 to +125	°C
Junction temperature		+150	°C
Package temperature (IR re	flow, peak)	+250	°C

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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## **ELECTRICAL CHARACTERISTICS**

All specifications at  $T_A$  = +25°C,  $V_{CC}$  = 13 V,  $R_{IDRV}$  = 90 k $\Omega$ , and  $C_{LOAD}$  = 22 pF, unless otherwise noted.

			V			
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER	SUPPLY	•	•			
V <sub>CC</sub>	Supply voltage		10	13	16	V
I <sub>CC</sub>	Supply current			2		mA
DYNAM	IC PERFORMANCE					
	Gain	1-MHz, 200-mV <sub>PP</sub> input		0.999		ns
	Rise time	V <sub>IN</sub> = 7.5 V to 8.5 V		5		ns
	Fall time	V <sub>IN</sub> = 8.5 V to 7.5 V		6		ns
	I/O delay time	V <sub>IN</sub> = 7.5 V to 8.5 V		1.28		ns
	-3-dB bandwidth	100-mV <sub>PP</sub> input		210		MHz
V <sub>IN</sub>	Input voltage range	V <sub>CC</sub> = 13 V	1.5		10.5	V
T <sub>A</sub>	Operating free-air temperature		0		+85	°C

## THERMAL INFORMATION

		VSP1000	
	THERMAL METRIC <sup>(1)</sup>	DSF	UNITS
		6 PINS	
$\theta_{JA}$	Junction-to-ambient thermal resistance	333.2	
$\theta_{JCtop}$	Junction-to-case (top) thermal resistance	56.9	
$\theta_{JB}$	Junction-to-board thermal resistance	239	°C/W
ΨЈТ	Junction-to-top characterization parameter	13.9	C/VV
$\Psi_{JB}$	Junction-to-board characterization parameter	236	
$\theta_{JCbot}$	Junction-to-case (bottom) thermal resistance	202	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

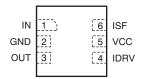
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#### **PIN CONFIGURATION**

DSF PACKAGE 1-mm × 1-mm × 0.35-mm QFN-6 (TOP VIEW)



#### **PIN ASSIGNMENTS**

PIN NAME	PIN NUMBER	TYPE	TYPE DESCRIPTION					
IN	1	Analog input	Input terminal; connect this pin to the sensor output					
VEE	2	Ground	Negative supply terminal; must be connected to ground					
OUT	3	Analog output	Output terminal; connect this pin to the AFE input					
IDRV	4	Analog input	Drive current adjustment; refer to the application diagram for further details					
VCC			Positive supply terminal; must be decoupled to the VEE terminal with a 0.1-µF capacitor					
ISF	6	Analog input	Sink current adjustment; refer to the application diagram for further details					

# **FUNCTIONAL BLOCK DIAGRAM**

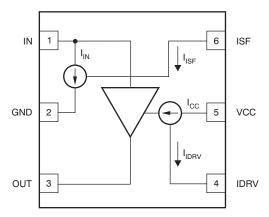
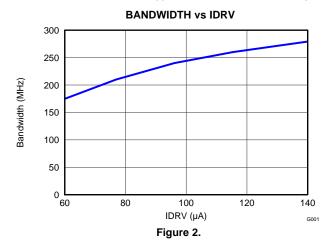


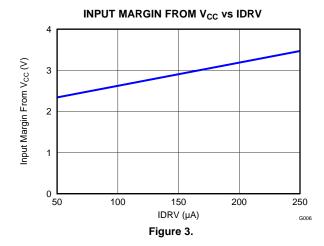
Figure 1. Block Diagram

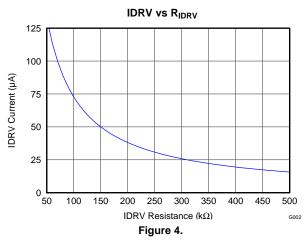


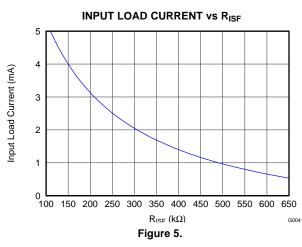
#### TYPICAL CHARACTERISTICS

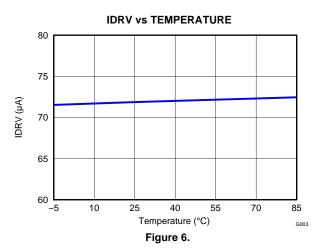
At  $T_A$  = +25°C,  $V_{CC}$  = 13 V,  $R_{IDRV}$  = 90 k $\Omega$ ,  $R_{ISF}$  = 300 k $\Omega$ , and  $C_{LOAD}$  = 22 pF, unless otherwise noted.

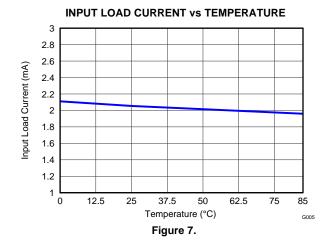








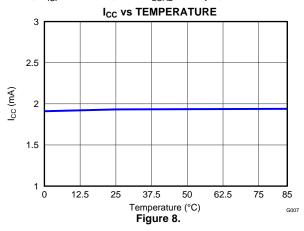






# **TYPICAL CHARACTERISTICS (continued)**

At  $T_A$  = +25°C,  $V_{CC}$  = 13 V,  $R_{IDRV}$  = 90 k $\Omega$ ,  $R_{ISF}$  = 300 k $\Omega$ , and  $C_{LOAD}$  = 22 pF, unless otherwise noted.



## **OVERVIEW**

# **TYPICAL APPLICATION CIRCUIT**

Figure 9 shows a typical application circuit for the VSP1000.

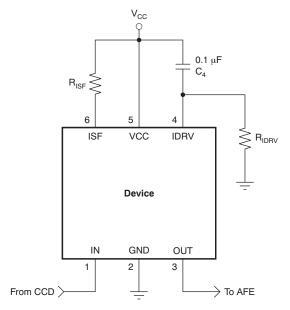


Figure 9. Typical Application Circuit

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#### **DESIGN EQUATIONS**

The CCD outputs must be loaded with current for proper operation. The VSP1000 provides the ability to draw adjustable current through the IN pin. The value of the input load current can be set by choosing an appropriate value of  $R_{\rm ISF}$  connected to the ISF pin, as per Equation 1.

$$I_{IN} = \frac{\left(\frac{(V_{CC} \times 100 \text{ k}\Omega)}{(R_{ISF} + 100 \text{ k}\Omega)}\right) - 1.2}{1 \text{ k}\Omega}$$
(1)

The bandwidth of the VSP1000 can be adjusted using the IDRV pin. The resistor connected at IDRV determines the drive strength of the output buffer as well as the total quiescent current of the VSP1000. Equation 2 and Equation 3 describe the relationship between  $R_{\text{IDRV}}$  and the drive strength.  $C_{\text{IDRV}}$  is used to increase the power-supply rejection ratio of the device. A value of 0.1  $\mu$ F for  $C_{\text{IDRV}}$  is recommended.

$$I_{DRV} = \frac{(V_{CC} - 5)}{(R_{IDRV} + 10 \text{ k}\Omega)}$$
(2)

$$I_{CC} = 26 \times I_{DRV} \tag{3}$$

#### **EXAMPLE CONFIGURATIONS**

Table 1 details several example configurations for the VSP1000. All examples are with  $V_{CC} = 13 \text{ V}$ .

CONFIGURATION I<sub>CC</sub> (mA)  $R_{ISF}(k\Omega)$  $R_{IDRV}$  ( $k\Omega$ ) Bandwidth = 170 MHz ,  $I_{IN}$  = 2 mA 1.5 300 133 Bandwidth = 170 MHz ,  $I_{IN}$  = 4 mA 1.5 133 150 2 Bandwidth = 210 MHz ,  $I_{IN}$  = 2 mA 300 91 2 150 91 Bandwidth = 210 MHz ,  $I_{IN}$  = 4 mA 3 Bandwidth = 260 MHz ,  $I_{IN}$  = 2 mA 300 62 3 Bandwidth = 260 MHz ,  $I_{IN}$  = 4 mA 150 62

**Table 1. Example Configurations** 

#### **LAYOUT GUIDELINES**

The decoupling capacitors C<sub>IDRV</sub>, R<sub>IDRV</sub>, and R<sub>ISF</sub> should be placed as close as possible to the VSP1000.

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# **REVISION HISTORY**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Cł	hanges from Original (September 2011) to Revision A	Page
•	Updated Figure 4	5
•	Updated Figure 5	5



# PACKAGE OPTION ADDENDUM

10-Dec-2020

#### PACKAGING INFORMATION

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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
VSP1000DSFR	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	0 to 85	VK	Samples
VSP1000DSFT	ACTIVE	SON	DSF	6	250	RoHS & Green	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	0 to 85	VK	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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10-Dec-2020

# PACKAGE MATERIALS INFORMATION

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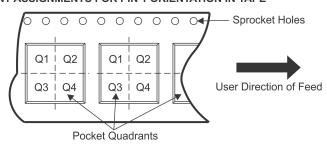
# TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
I	VSP1000DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.63	4.0	8.0	Q2
Ī	VSP1000DSFT	SON	DSF	6	250	180.0	9.5	1.16	1.16	0.63	4.0	8.0	Q2

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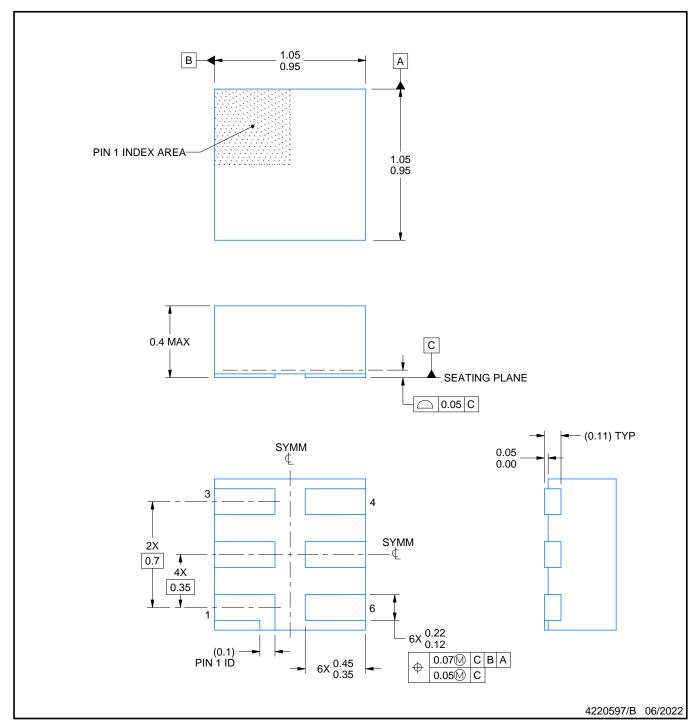


#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
VSP1000DSFR	SON	DSF	6	5000	184.0	184.0	19.0
VSP1000DSFT	SON	DSF	6	250	184.0	184.0	19.0



PLASTIC SMALL OUTLINE - NO LEAD



#### NOTES:

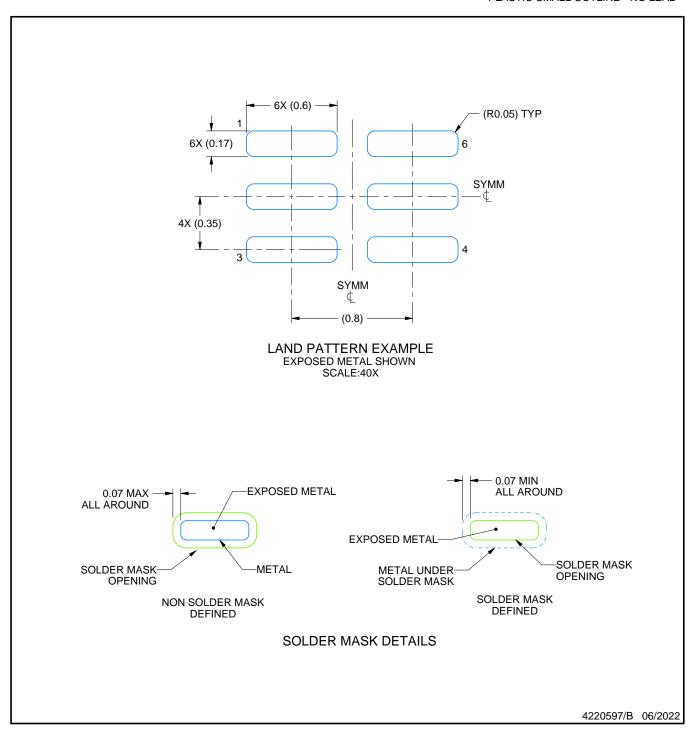
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. Reference JEDEC registration MO-287, variation X2AAF.



PLASTIC SMALL OUTLINE - NO LEAD

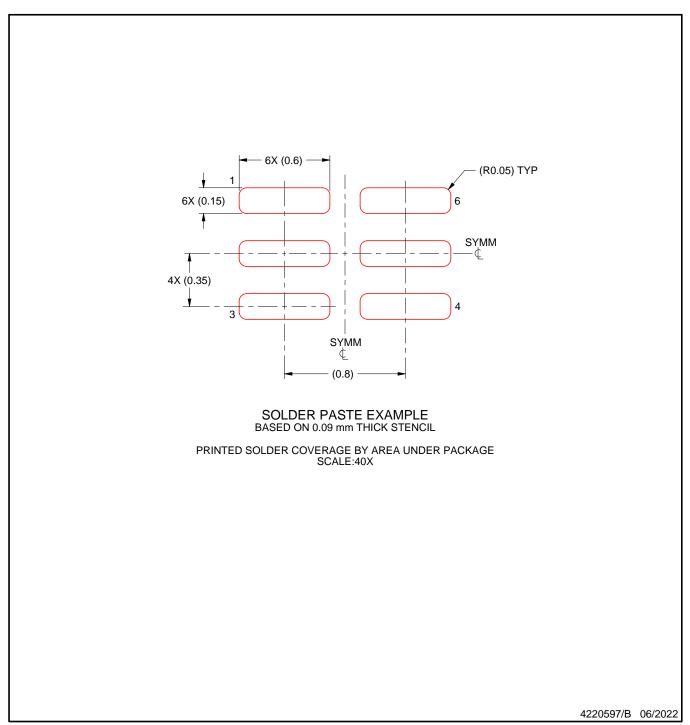


NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC SMALL OUTLINE - NO LEAD



4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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